

Theory for supersolid ^4He

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Although both vacancies and interstitials have relatively high activation energies in the normal solid, we propose that a lower energy bound state of a vacancy and an interstitial may facilitate vacancy condensation to give supersolidity in ^4He . We use a phenomenological two-band boson lattice model to demonstrate this new mechanism and discuss the possible relevance to the recently observed superfluid-like, non-classical rotational inertial experiments of Kim and Chan in solid ^4He . Some of our results may also be applicable to trapped bosons in optical lattices.

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Recently Kim and Chan have reported observation of superfluid-like, non-classical rotational inertial (NCRI) behavior in solid ^4He , both when embedded in Vycor glass [1] and in bulk ^4He [2]. Their experiments have revived great interest in supersolidity with both crystalline and superfluid orderings in helium. The possibility of a supersolid phase in ^4He was theoretically proposed by Chester [3], Leggett [4], Saslow [5] and by Adreeve and Lifshitz [6] in 1970's. Adreeve and Lifshitz proposed Bose condensation of vacancies as the mechanism for supersolidity. Chester speculated that supersolidity cannot exist without vacancies and/or interstitials [3], a claim made more rigorous recently by Prokofev and Svistunov [7]. Experiments and more sophisticated microscopic calculations have, however, provided constraints to any theory for supersolid in ^4He . The NMR experiments [8, 9] on solid ^3He rule out a non-negligible zero point vacancy concentration. The energy of a vacancy in solid ^4He was estimated to be about $10K$ by the x-ray scattering experiment [10] and to be $15K$ in a theoretical calculation [11]. The energy of a pure interstitial state has recently been calculated to be about $48 \pm 5K$ [12]. Assuming that the observed supersolidity is a genuine bulk phenomenon, the quandary is thus how defects with such high activation energies can condense at low temperature.

In this Letter, we propose a possible solution to this quandary. In addition to vacancies and interstitials, there is a third type of defects, with relatively low excitation energy, which corresponds to a bound state of a vacancy and an interstitial, henceforth called an "exciton". While such excitons do not carry mass and will not contribute to supersolid phenomena like those observed by Kim and Chan [1, 2], they can facilitate supersolidity by two mechanisms. First, vacancies can condense above a background of excitons easier than above the defect free (DF) normal state, so that the condensation energy can more than compensate for the exciton excitation energy. Second, in a background formed of a coherent mixture of the DF state and the exciton, the effective kinetic energy of vacancies and interstitials can be enhanced due to constructive interference between hopping processes involving the DF state and those involving the exciton.

The essence of our theory is that while, consistent with all known experiments, the normal solid state is the DF state, the supersolid state results from condensation of vacancies and/or interstitials about a defect rich background of excitons. This physics is shown quantitatively using a phenomenological two-band lattice boson model to represent the defects in solid ^4He . Using mean field theory (MFT), we show that superfluidity in solid helium can exist in parameter regimes qualitatively consistent with all the known experiments and microscopic calculations. We will argue that the key results will hold beyond MFT, and indeed are rendered more robust by inclusion of quantum fluctuations. Because of the "vacuum switching" between the normal and supersolid states, the transition at zero temperature is generically first order.

We start with the lattice as defined by the periodicity of crystalline helium. On each lattice site, we consider two single-particle localized states. The lower energy state (a -state), with energy $-\epsilon_a$, has its maximum on the lattice site. The other state (b -state), with a higher energy $-\epsilon_a + \Delta$, is less localized and has maxima distributed with hcp symmetry away from the lattice site. Because of the strongly repulsive cores, each of this state can hold at most one ^4He atom, i.e. for each state, helium behaves as hard core bosons. On the other hand, because of the spatial separation between the a and b states, an atom in the a -state repels one in the b -state with a large but weaker strength U . An atom on one site can tunnel to a neighboring site from a to a -state, b to b -state, and a to b state with hopping amplitudes t_a , t_b , and t_{ab} respectively, taken all to be real and non-negative. In the DF state, we have one helium atom occupying the a -state on each lattice site. Due to the hard core condition, the ^4He atoms in this state are immobile, and this state is a normal solid, which is consistent with the assumption that defects are necessary for supersolid. To study defects, it is convenient to consider the DF state as the defect vacuum state, from which vacancies and interstitials can be created. The term vacuum will always refer to the DF state henceforth in this article. Let $a_i^\dagger$ be the creation operator for the vacancy by removing a helium atom from this vacuum state at the site i , and $b_i^\dagger$

the creation operator for the interstitial by creating an atom to the b -state on the site. Note that the interstitial defined this way can be viewed as a quantum generalization of the classical interstitial. The hard core conditions specified above implies these operators are also hard core boson operators. Our model Hamiltonian for defects in solid helium is then,

$$H = \sum_j \epsilon_a n_{j,a} + \epsilon_b n_{j,b} - U n_{j,a} n_{j,b} - \sum_{\langle ij \rangle} (t_a a_i^\dagger a_j + t_b b_i^\dagger b_j + t_{ab} a_i^\dagger b_j^\dagger + h.c.) \quad (1)$$

In the above equation, $n_{j,a} = a_j^\dagger a_j$, $n_{j,b} = b_j^\dagger b_j$, and ϵ_a (previously defined) and ϵ_b are the energy cost to create a helium vacancy and an interstitial respectively. The repulsion U between He atoms translates into an attraction of strength U between a vacancy and an interstitial on the same site. The energy of a localized exciton is $\Delta = \epsilon_a + \epsilon_b - U$. For simplicity, in what follows we will consider $t_{ab} = 0$.

To illuminate the effects of excitons, let's first discuss the non-interacting case $U = 0$. In this limit, the vacancies and interstitials are decoupled. For $\epsilon_b \rightarrow \infty$, our model is reduced to the vacancy model proposed by Andreev and Lifshitz [6]. Let $z(=12)$ be the number of the nearest neighbors in a hcp lattice, the onset of Bose condensation of vacancies (interstitials) is given exactly by $\epsilon_{a(b)} - z t_{a(b)} = 0^-$, which coincides with having zero activation energy for a single defect, a condition that is not supported by experiments[10] and theoretical estimates[11, 12] for ^4He . This is the quandary we stated in the introduction.

We now consider the case $U > 0$. In this case, a vacancy and an interstitial tend to bind together to form a local exciton. If the exciton energy Δ is small (large U), the presence of the excitons in the ground state enhances the kinetic energy of the vacancy (or interstitial), which may lead to the condensation of these defects. Since we are primarily interested in the large U case, it is important to treat the on-site attractive interaction accurately. In order to do so, we use the single-site mean field approximation (MFA) by decoupling the kinetic terms as

$$\begin{aligned} a_i^\dagger a_j &\approx \bar{a}(a_j + a_i^\dagger) - \bar{a}^2, \\ b_i^\dagger b_j &\approx \bar{b}(b_j + b_i^\dagger) - \bar{b}^2 \end{aligned} \quad (2)$$

where the spatially uniform Bose condensation order parameters $\bar{a} = \langle a_i \rangle$ and $\bar{b} = \langle b_i \rangle$ are determined self-consistently. The single site mean field Hamiltonian for the hard core bosons are then solved exactly. This MFA gives the correct exact conditions for onset of superfluidity at $U = 0$.

The ground state phase diagrams obtained within the MFA in the parameter space t_a and t_b are shown in Fig. 1(a) for $\epsilon_a = \epsilon_b = 1$, $U = 1.9$ and in Fig. 1(b) for $\epsilon_a = 1$, $\epsilon_b = 4$, and $U = 4.8$. They represent a more symmetric and a strongly asymmetric cases respectively. Within

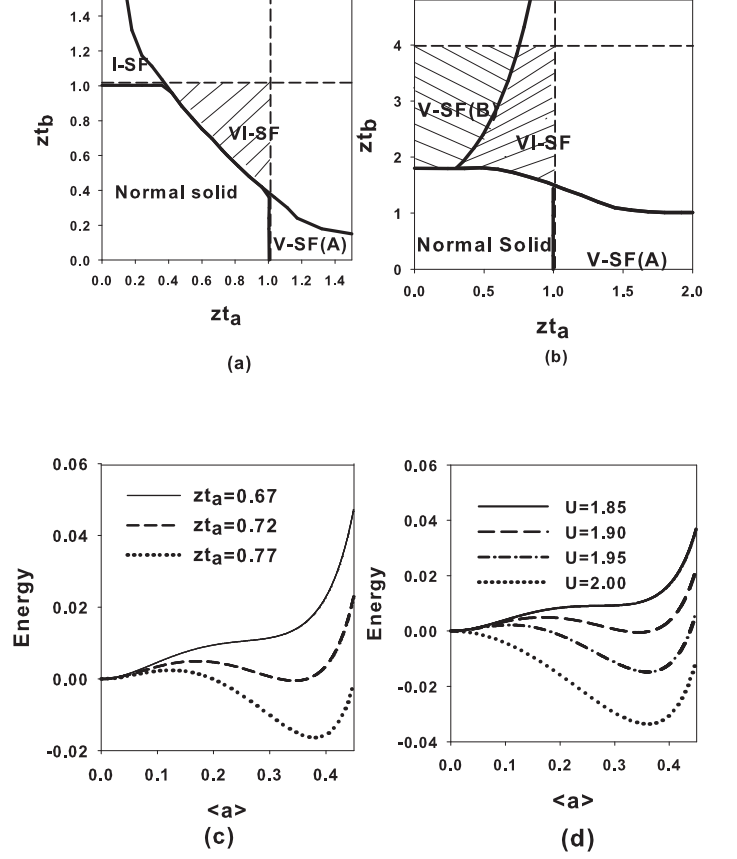


FIG. 1: (a) Mean field theory phase diagram of Hamiltonian (1) in the symmetric case with $\epsilon_a = \epsilon_b = 1$ and $U = 1.9$. V-SF (I-SF): vacancy (interstitial) superfluid phase. (b) Same as in (a) in the asymmetric case $\epsilon_a = 1$, $\epsilon_b = 4$ and $U = 4.8$. See Fig. 2 for the snapshots of these phases in real space. (c) The variational energy of the symmetric model with $\epsilon_a = \epsilon_b = 1$ and $U = 1.9$ as a function of the SF order parameter for $t = t_a = t_b = 0.056$ (normal solid phase), $t = 0.06$ (at the phase boundary) and $t = 0.064$ (VI-SF phase). (d) Same as in (c) with $t_a = t_b = 0.06$ for various values of U .

the MFA, we found five different phases, characterized by the order parameters $\bar{a}$ and $\bar{b}$ together with the vacuum, vacancy, interstitial, and exciton defect densities n_0, n_V, n_I , and n_{ex} . They are (1) The normal DF solid phase. (2) The vacancy superfluid phase (V-SF(A)), where only the vacancies condense ($\bar{a} \neq 0$) above the DF background ($n_I = n_{ex} = 0$). This phase is the same as the vacancy state of Andreev and Lifshitz. (3) The corresponding interstitial superfluid phase (I-SF). (4) An alternative vacancy superfluid phase (V-SF(B)), where the vacancies condense above a background of excitons. (5) The VI-SF phase, where we have both vacancies and interstitials condensing above a background of a coherent mixture of

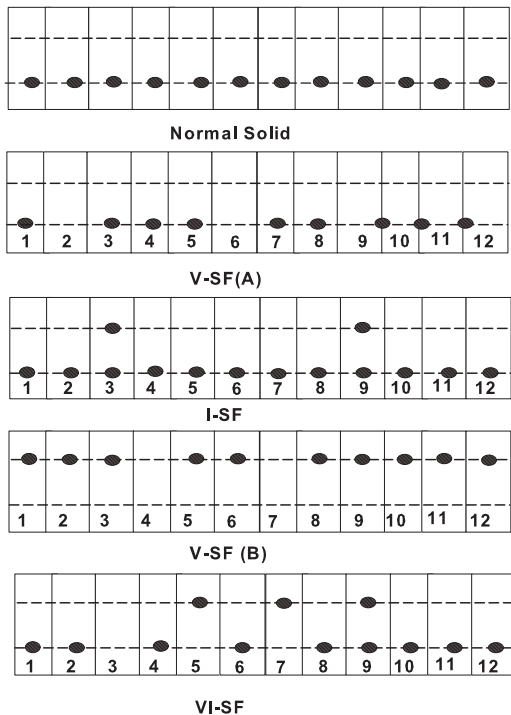


FIG. 2: Schematic illustration of snapshots of five phases shown in fig.1(a) and (b) in terms of the occupation of helium atoms at the lattice sites. A lattice site is represented by a numbered block. A solid dot represents a helium atom. At each site, emptiness represents a vacancy, occupation at the lower (higher) level represents a vacuum (exciton), and occupation at the both levels represents an interstitial.

the vacuum and the exciton. A snapshot of each of these phases in terms of the occupation of helium atoms in real space is illustrated in Fig. 2.

To appreciate the phase diagrams and the new physics arising from the interaction U , we show the phase boundaries of the non-interacting model ($U = 0$) by dashed lines in Fig. 1(a) and (b). As remarked earlier, these boundaries coincide with the vanishing of the activation energy of an isolated vacancy or interstitial. Since U plays no role if only vacancies or only interstitials are present, these are also the phase boundaries for normal solid to V-SF(A) or I-SF transition even for $U > 0$. Thus, for such SF states, their corresponding normal (i.e. uncondensed) states are not the DF state but contain a finite density of defects, which is not the case for super-solid ^4He . The most striking of our results is that the interplay between vacancies (and/or interstitials) and exciton defects can lead to SF even in parameter regimes where the normal state is stable against the generation of uncondensed defects (hatched areas in the figures). We propose this as the reconciliation between activated defect behavior at high temperature (T) and supersolidity

at low T in ^4He . In the hatched regime, the DF state is metastable but not the global minimum energy state. In Fig. 1(c) and 1(d), we illustrate this by plotting the variational energy $E(\bar{a})$ based on the MFA [13] for the symmetric model with $t_a = t_b = t$, so that $\bar{a} = \bar{b}$, with increasing t (Fig.1(c)) and U (Fig.1(d)). The existence of two minima are clearly seen. With increasing t or U , the Bose condensed state becomes lower in energy than the normal state in the hatched areas. The transition is first order due to "vacuum switching": the normal state at $\bar{a} = 0$ is the DF state with no excitons ($n_{ex} = 0$), while the background that vacancies and interstitials condense above to form the VI-SF is the one with a finite density of excitons ($n_{ex} \neq 0$). In what follows we discuss in more details the physics of the asymmetric and symmetric cases, focusing on the parameter regimes of the hatched areas.

Due to the high He atom density and strong repulsive cores, solid ^4He should fit the very asymmetric case with $\epsilon_b/\epsilon_a \gg 1$ in our model (Fig. 1(b)). Because the b -state is less localized compared to the a -state and because of the exponential dependence of the overlap integral on state size, we expect $t_b \gg t_a$. For small t_a , the phase in the hatched region is the V-SF(B) phase. To understand how this phase comes about, we consider first $t_a = 0$. Here, the activation energies of a vacancy and an exciton are ϵ_a and Δ respectively independent of t_b , so the DF state is locally stable. Since $t_a = 0$, vacancies cannot hop, and there is no possibility of vacancy condensation above the DF state. However, if we take a background of excitons on every site, then vacancies can now hop with amplitude t_b , and the exciton state can be unstable with respect to a vacancy condensation that gives $\bar{b} \neq 0$. The onset of this V-SF(B) instability is $zt_b = \epsilon_a - \Delta$. For t_b greater than this value, $E(\bar{b})$ has a double minima behavior similar to that shown in Fig 1(c) for the symmetric case, with $E(\bar{b} = 0)$ initially the lower energy. However, as t_b increases (but still less than the value necessary for spontaneous generation of interstitials), the vacancy condensation energy can become large enough to overcome the required vacancy and exciton activation energies given by $n_V \epsilon_a + (1 - n_V) \Delta$, and a first order transition from the normal DF state to the V-SF(B) state occurs. Note that the transition is accompanied by a "vacuum switching", in that the vacancies are condensing not above the DF state, but above the exciton state. The V-SF(B) has $\bar{b} \neq 0$, and $n_V + n_{ex} = 1$. As t_a increases, it becomes advantageous to mix in some vacuum component to allow vacancy hopping through t_a , so that both $\bar{a}$ and $\bar{b}$ are non-zero. Depending on the value ϵ_b , some interstitial condensation will also occur. The V-SF(B) phase then makes a second order transition into the VI-SF, characterized by both $\bar{a}$ and $\bar{b} \neq 0$, and n_V, n_I, n_{ex} all $\neq 0$. We will discuss this phase further in the symmetric case, where it will feature more prominently. In this strongly asymmetric case, whether we take the SF state to be the V-SF(B) or the VI-SF state, we have $n_V \gg n_I$. Thus, a prediction of our theory is

that while the normal state is a commensurate solid, the supersolid will have incommensurate density, which can be confirmed by neutron scattering experiments in the supersolid phase. Furthermore, because of the presence of excitons in the supersolid (i.e. the He atom resides in the less localized b - state rather than the a - state, or some linear combination of the two), the local He density in a unit cell will change with the transition into the supersolid. This can be confirmed from the form factor of neutron scattering or with a local probe.

Next we look at the symmetric case. Although this probably does not describe solid ^4He , it may be applicable to a system of trapped bosons in an optical lattice, where the periodic potential is imposed externally rather than internally generated. In such a system, the ratio ϵ_b/ϵ_a can be tuned by tuning the optical potential. The interesting phase here is the VI-SF phase in the hatched region. Again, the key question is what causes the additional non-trivial SF solution since neither vacancy nor the interstitial alone can condense at $T = 0$. Unlike the asymmetric case, where n_I in this phase basically plays no role, and indeed $\rightarrow 0$ as $\epsilon_b \rightarrow \infty$, here, n_0, n_V, n_I, n_{ex} are all non-negligible in this SF phase. Within the MFA, the eigenstates are direct product of single-site states. In this ground state, the state on each site is a coherent mixture of the DF state, the vacancy, the interstitial, and the exciton. This coherence allows constructive interference between the various hopping processes, thus enhancing the effect of kinetic energy over that when only vacancies or interstitials are present or when they hop in a background of only DF states or only exciton states. This coherent effect is best understood by examining the highly symmetric case of $\epsilon_b = \epsilon_a = \epsilon$, $t_b = t_a = t$ and $U = 2\epsilon_a$ (so that $\Delta = 0^+$). By symmetry, we also have $\bar{a} = \bar{b}$. Because of the symmetry between the vacancy and the interstitial, and between the vacuum and the exciton states, the MF energy $E_{MF}(\bar{a})$ can be analytically found to be $\frac{\epsilon}{2} - \sqrt{(\frac{\epsilon}{2})^2 + (2zt\bar{a})^2 + 2zt\bar{a}^2}$, from which the condition for the SF state is found to be $\epsilon - 2zt < 0$. Compared with the SF condition for vacancy only condensation above the DF background, we see that the effective hopping integral increases from t to $2t$ due to the coherent mixture of all 4 states. For this artificial highly symmetric case, the normal to VI-SF transition is second order due to Δ being infinitesimal. As Δ increases, the transition becomes first order. This is what is shown in Fig 1c as the transition is crossed by increasing t . Alternatively, the transition can be crossed by increasing U , as shown in Fig 1(d).

Although our results so far are obtained using the MFA, we believe the central conclusion, that supersolid can occur even when defects like vacancies and interstitials have relatively high activation energies is correct. In the lattice model of (1), the excitations in the supersolid phase are gapless and the excitations in the normal solid are gapped. Therefore, the quantum fluctuations are expected to further stabilize the supersolid phase. In our

MFT, there are four supersolid phases in terms of the order parameters $\bar{a}$ and $\bar{b}$. However, there is no difference between them in the type of off diagonal ordering of the underlying ^4He atoms. Thus, they are not really distinct phases in the sense of different symmetry states, but rather differ in the physics behind the condensation as discussed above. Indeed, if fluctuations are included or if we consider non-zero t_{ab} , then the sharp distinction between these "phases" becomes crossover.

Following Leggett's paper [4], we can derive the SF density detected by the NCRI experiment, which is

$$\rho_S = \rho_a m_0 / m_a^* + \rho_b m_0 / m_b^*, \quad (3)$$

where m_a^* and m_b^* are the effective mass of the vacancy and interstitial bands respectively determined by the hopping integral t_a and t_b and the lattice structure, and m_0 is the bare mass of ^4He . For the purpose of illustration, we will assume that $m_b^* = m_0$ at the value of $t_b = 1/3$. Because the transition at $T = 0$ is first order, the SF density has an abrupt jump at the criticality. For reasonable values of parameters $\epsilon_a = 1$, $\epsilon_b = 4$, $t_a = 0.07$ and $t_b = 0.2$, we find the jump to be $\sim 9\%$, which is about an order larger than the SF density measured in Kim and Chan's experiments[2]. The discrepancy is partly due to the simplicity of the model. For instance, the critical SF density ρ_S is found to be $\sim 3\%$ by including an on-site interband hopping $t_{ab}^0 = 0.12$. Furthermore, the quantum phase fluctuations mentioned above will decrease ρ_S at criticality by the dual effects of directly decreasing the order parameters and by reduction of the critical value U_c due to stabilizing of the SF phase relative to the DF state. We also note that the experiments of Kim and Chan are performed on granular rather than single crystal, so that the observed ρ_S may be governed by Josephson effect and therefore can be considerably smaller than the intrinsic value of homogenous supersolid ^4He .

We have seen that the $T=0$ transition should be first order. A careful examination of the finite T transition should include also the effect of phase fluctuations. The finite T transition as well as the collective excitations in the various SF phases of our model will be discussed in a future publication.

In conclusion, we have proposed a solution to how ^4He can become a supersolid at low T when both vacancies and interstitials have relatively high activation energies in the normal solid. In our theory, the presence of low energy bound vacancy-interstitial defects facilitate the condensation of vacancies. In this theory, the normal state is a commensurate solid while the supersolid is incommensurate. Furthermore, the local helium density in the unit cell has different profiles in the two phases. These predictions can be tested experimentally.

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